74ABT125

Quad buffer; 3-state

Rev. 6 — 3 November 2011

Product data sheet

1. **General description**

The 74ABT125 high-performance BiCMOS device combines low static and dynamic power dissipation with high speed and high output drive.

The 74ABT125 device is a quad buffer that is ideal for driving bus lines. The device features four Output Enables (1OE, 2OE, 3OE, 4OE), each controlling one of the 3-state outputs.

Features and benefits 2.

- Quad bus interface
- 3-state buffers
- Live insertion and extraction permitted
- Output capability: HIGH –32 mA; LOW +64 mA
- Power-up 3-state
- Inputs are disabled during 3-state mode
- Latch-up protection exceeds 500 mA per JESD78 class II level A
- ESD protection:
 - HBM JESD22-A114E exceeds 2000 V
 - ♦ MM JESD22-A115-A exceeds 200 V

Ordering information 3.

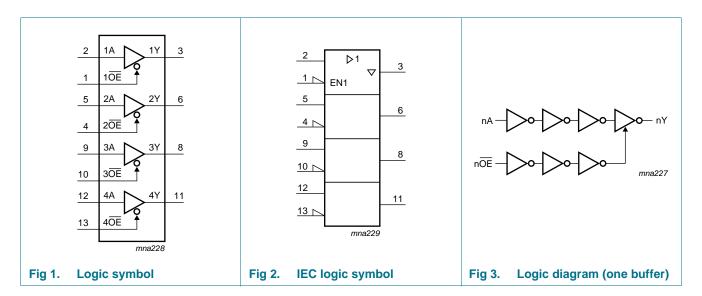
Table 1. **Ordering information**

| Type number | Package | | | | | | | | |
|-------------|-------------------|----------|--|----------|--|--|--|--|--|
| | Temperature range | Name | Description | Version | | | | | |
| 74ABT125N | –40 °C to +85 °C | DIP14 | plastic dual in-line package; 14 leads (300 mil) | SOT27-1 | | | | | |
| 74ABT125D | −40 °C to +85 °C | SO14 | plastic small outline package; 14 leads; body width 3.9 mm | SOT108-1 | | | | | |
| 74ABT125DB | –40 °C to +85 °C | SSOP14 | plastic shrink small outline package; 14 leads; body width 5.3 mm | SOT337-1 | | | | | |
| 74ABT125PW | –40 °C to +85 °C | TSSOP14 | plastic thin shrink small outline package; 14 leads; body width 4.4 mm | SOT402-1 | | | | | |
| 74ABT125BQ | –40 °C to +85 °C | DHVQFN14 | plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body $2.5\times3\times0.85$ mm | SOT762-1 | | | | | |



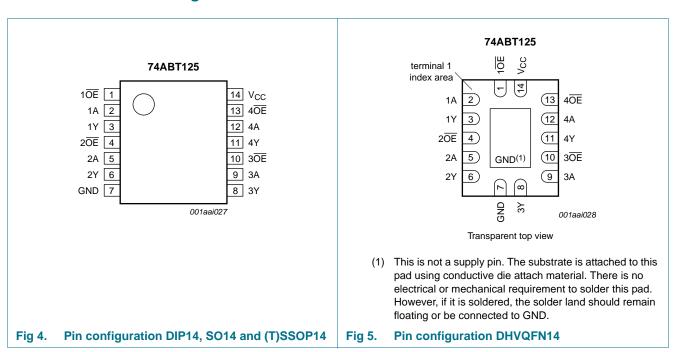
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4. Functional diagram



5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

| Symbol | Pin | Description |
|-----------------|--------------|----------------------------------|
| 1OE to 4OE | 1, 4, 10, 13 | output enable input (active LOW) |
| 1A to 4A | 2, 5, 9, 12 | data input |
| 1Y to 4Y | 3, 6, 8, 11 | data output |
| GND | 7 | ground (0 V) |
| V _{CC} | 14 | supply voltage |

6. Functional description

Table 3. Function selection[1]

| Inputs nOE | Output | |
|---------------|--------|----|
| nOE | nA | nY |
| L | L | L |
| L | Н | Н |
| Н | X | Z |

^[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

7. Limiting values

Table 4. Limiting values[1]

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|-------------------------|---|--------------|------|------|
| V_{CC} | supply voltage | | -0.5 | +7.0 | V |
| VI | input voltage | | -1.2 | +7.0 | V |
| Vo | output voltage | output in OFF-state or HIGH-state | -0.5 | +5.5 | V |
| I _{IK} | input clamping current | V _I < 0 V | -18 | - | mA |
| I _{OK} | output clamping current | V _O < 0 V | -50 | - | mA |
| Io | output current | output in LOW-state | - | 128 | mA |
| Tj | junction temperature | | [2] _ | 150 | °C |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| P _{tot} | total power dissipation | $T_{amb} = -40 ^{\circ}\text{C} \text{ to } +85 ^{\circ}\text{C}$ | <u>[3]</u> _ | 500 | mW |

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

^[2] The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability.

^[3] SO14 packages: above 70 °C P_{tot} derate linearly with 8 mW/K SSOP14 and TSSOP20 packages: above 60 °C P_{tot} derate linearly with 5.5 mW/K DHVQFN14 packages: above 60 °C P_{tot} derate linearly with 4.5 mW/K

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8. Recommended operating conditions

Table 5. Operating conditions

Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|---------------------|-------------------------------------|-------------|-----|----------|------|
| V_{CC} | supply voltage | | 4.5 | 5.5 | V |
| VI | input voltage | | 0 | V_{CC} | V |
| V_{IH} | HIGH-level input voltage | | 2.0 | - | V |
| V_{IL} | LOW-level Input voltage | | - | 0.8 | V |
| I _{OH} | HIGH-level output current | | -32 | - | mA |
| I _{OL} | LOW-level output current | | - | 64 | mA |
| $\Delta t/\Delta V$ | input transition rise and fall rate | | - | 10 | ns/V |
| T _{amb} | ambient temperature | in free air | -40 | +85 | °C |

9. Static characteristics

Table 6. Static characteristics

| Symbol | Parameter | Conditions | | 25 °C | | | -40 °C t | Unit | |
|-----------------------|------------------------------------|---|------------------------------------|-------|-------|------|----------|------|----|
| | | | | Min | Тур | Max | Min | Max | |
| V_{IK} | input clamping voltage | $V_{CC} = 4.5 \text{ V}; I_{IK} = -18 \text{ mA}$ | | - | -0.9 | -1.2 | - | -1.2 | V |
| V_{OH} | HIGH-level output | $V_I = V_{IL}$ or V_{IH} | | | | | | | |
| | voltage | $V_{CC} = 4.5 \text{ V}; I_{OH} = -3 \text{ mA}$ | | 2.5 | 2.9 | - | 2.5 | - | V |
| | | V_{CC} = 5.0 V; I_{OH} = -3 mA | | 3.0 | 3.4 | - | 3.0 | - | V |
| | | $V_{CC} = 4.5 \text{ V}; I_{OH} = -32 \text{ mA}$ | | 2.0 | 2.4 | - | 2.0 | - | V |
| V_{OL} | LOW-level output voltage | V_{CC} = 4.5 V; I_{OL} = 64 mA; V_I = V_{IL} or V_{IH} | V _{IL} or V _{IH} | | 0.35 | 0.55 | - | 0.55 | V |
| I _I | input leakage current | $V_{CC} = 5.5 \text{ V}; V_{I} = \text{GND or } 5.5 \text{ V}$ | | - | ±0.01 | ±1.0 | - | ±1.0 | μΑ |
| I _{OFF} | power-off leakage current | V_{CC} = 0.0 V; V_{I} or $V_{O} \le 4.5$ V | | - | ±5.0 | ±100 | - | ±100 | μΑ |
| I _{O(pu/pd)} | power-up/power-down output current | V_{CC} = 2.1 V; V_O = 0.5 V; V_I = GND or V_{CC} ; \overline{OE} = don't care | [1] | - | ±5.0 | ±50 | - | ±50 | μΑ |
| l _{OZ} | OFF-state output | $V_{CC} = 5.5 \text{ V}; V_I = V_{IL} \text{ or } V_{IH}$ | | | | | | | |
| | current | V _O = 2.7 V | | - | 1.0 | 50 | - | 50 | μΑ |
| | | V _O = 0.5 V | | - | -1.0 | -50 | - | -50 | μΑ |
| I _{LO} | output leakage current | HIGH-state; $V_O = 5.5 \text{ V}$; $V_{CC} = 5.5 \text{ V}$; $V_I = \text{GND or } V_{CC}$ | | - | 5.0 | 50 | - | 50 | μΑ |
| Io | output current | $V_{CC} = 5.5 \text{ V}; V_O = 2.5 \text{ V}$ | [2] | -50 | -100 | -180 | -50 | -180 | mΑ |
| I _{CC} | supply current | V_{CC} = 5.5 V; V_I = GND or V_{CC} | | | | | | | |
| | | outputs HIGH-state | | - | 65 | 250 | - | 250 | μΑ |
| | | outputs LOW-state | | - | 12 | 15 | - | 30 | mΑ |
| | | outputs disabled | | - | 65 | 250 | - | 50 | μΑ |

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Table 6. Static characteristics ... continued

| Symbol | Parameter | Conditions | Conditions | | 25 °C | | | –40 °C to +85 °C | | |
|-----------------|---------------------------|---|------------|-----|-------|-----|-----|------------------|----|--|
| | | | | Min | Тур | Max | Min | Max | | |
| ΔI_{CC} | additional supply current | per control pin; $V_{CC} = 5.5 \text{ V}$; one control input at 3.4 V, other inputs at V_{CC} or GND | [3] | | | | | | | |
| | | outputs enabled | | - | 0.5 | 1.5 | - | 1.5 | mΑ | |
| | | outputs disabled | | - | 50 | 250 | - | 250 | mΑ | |
| | | one enable input at 3.4 V and other inputs at V_{CC} or GND; outputs disabled | | - | 0.5 | 1.5 | - | 1.5 | mA | |
| CI | input capacitance | $V_I = 0 \text{ V or } V_{CC}$ | | - | 4 | - | - | - | pF | |
| Co | output capacitance | outputs disabled; $V_O = 0 \text{ V or } V_{CC}$ | | - | 7 | - | - | - | pF | |

^[1] This parameter is valid for any V_{CC} between 0 V and 2.1 V, with a transition time of up to 10 ms. From V_{CC} = 2.1 V to V_{CC} = 5 V \pm 10 %, a transition time of up to 100 μ s is permitted.

10. Dynamic characteristics

Table 7. Dynamic characteristics

GND = 0 V. Test circuit is shown in Figure 8.

| Symbol | Parameter | Conditions | 25 °C; | V _{CC} = | 5.0 V | -40 °C to V _{CC} = 5.0 | Unit | |
|------------------|-------------------------------------|-------------------------|--------|-------------------|-------|------------------------------------|------|----|
| | | | | Тур | Max | Min | Max | |
| t _{PLH} | LOW to HIGH propagation delay | nA to nY, see Figure 6 | 1.0 | 2.8 | 4.1 | 1.0 | 4.6 | ns |
| t _{PHL} | HIGH to LOW propagation delay | nA to nY; see Figure 6 | 1.0 | 3.1 | 4.6 | 1.0 | 4.9 | ns |
| t _{PZH} | OFF-state to HIGH propagation delay | nOE to nY; see Figure 7 | 1.0 | 3.2 | 5.0 | 1.0 | 5.9 | ns |
| t _{PZL} | OFF-state to LOW propagation delay | nOE to nY; see Figure 7 | 1.0 | 4.2 | 6.2 | 1.0 | 6.8 | ns |
| t _{PHZ} | HIGH to OFF-state propagation delay | nOE to nY; see Figure 7 | 1.0 | 4.1 | 5.4 | 1.0 | 6.2 | ns |
| t _{PLZ} | LOW to OFF-state propagation delay | nOE to nY; see Figure 7 | 1.5 | 2.8 | 5.0 | 1.5 | 5.5 | ns |

^[2] Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

^[3] This is the increase in supply current for each input at 3.4 V.

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11. Waveforms

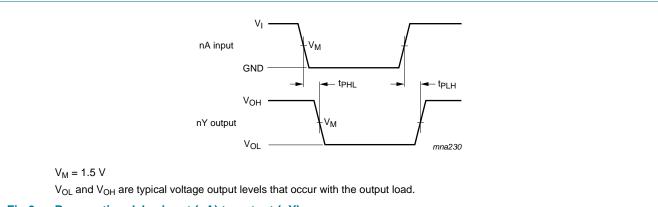
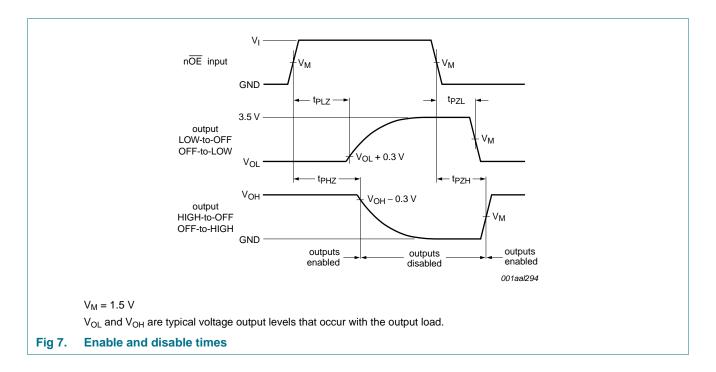
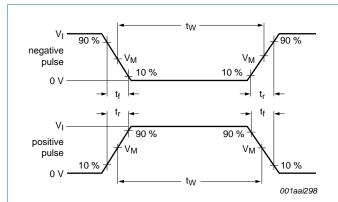
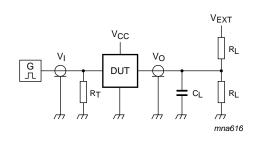


Fig 6. Propagation delay input (nA) to output (nY)



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b. Test circuit

a. Input pulse definition

Test data is given in Table 8.

Test circuit definitions:

 R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to output impedance Z_0 of the pulse generator.

V_{EXT} = Test voltage for switching times.

Fig 8. Load circuitry for switching times

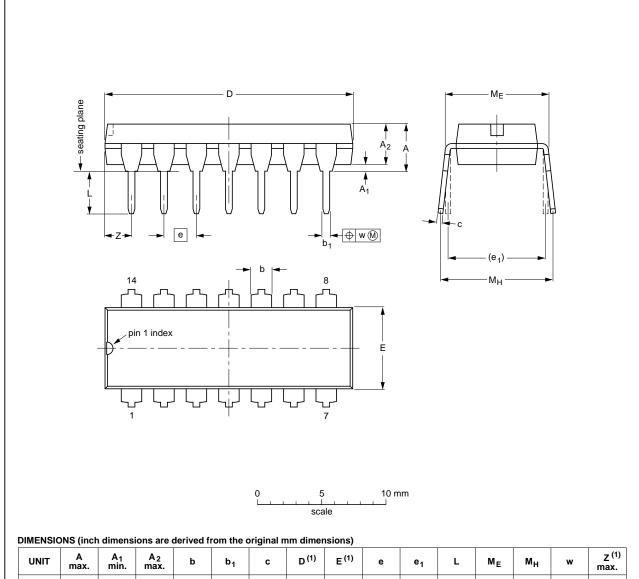
Table 8. Test data

| Input | Load | | V _{EXT} | | | | | |
|---------|------------------------|--------|------------------|-------|-------------------------------------|-------------------------------------|-------------------------------------|-------|
| V_{l} | f_l t_W t_r, t_f | | CL | R_L | t _{PHL} , t _{PLH} | t _{PZH} , t _{PHZ} | t _{PZL} , t _{PLZ} | |
| 3.0 V | 1 MHz | 500 ns | \leq 2.5 ns | 50 pF | 500Ω | open | open | 7.0 V |

12. Package outline

DIP14: plastic dual in-line package; 14 leads (300 mil)

SOT27-1



| UNIT | A max. | A ₁ min. | A ₂ max. | b | b ₁ | С | D ⁽¹⁾ | E ⁽¹⁾ | е | e ₁ | L | ME | M _H | w | Z ⁽¹⁾ max. |
|--------|-----------|------------------------|------------------------|----------------|----------------|----------------|------------------|------------------|------|----------------|--------------|--------------|----------------|-------|--------------------------|
| mm | 4.2 | 0.51 | 3.2 | 1.73 1.13 | 0.53 0.38 | 0.36 0.23 | 19.50 18.55 | 6.48 6.20 | 2.54 | 7.62 | 3.60 3.05 | 8.25 7.80 | 10.0 8.3 | 0.254 | 2.2 |
| inches | 0.17 | 0.02 | 0.13 | 0.068 0.044 | 0.021 0.015 | 0.014 0.009 | 0.77 0.73 | 0.26 0.24 | 0.1 | 0.3 | 0.14 0.12 | 0.32 0.31 | 0.39 0.33 | 0.01 | 0.087 |

Note

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

| OUTLINE | | REFER | RENCES | | EUROPEAN | ISSUE DATE | |
|---------|--------|--------|-----------|---|------------|---------------------------------|---|
| VERSION | IEC | JEDEC | JEITA | | PROJECTION | 1330E DATE | |
| SOT27-1 | 050G04 | MO-001 | SC-501-14 | | | 99-12-27 03-02-13 | |
| | | | • | • | | | • |

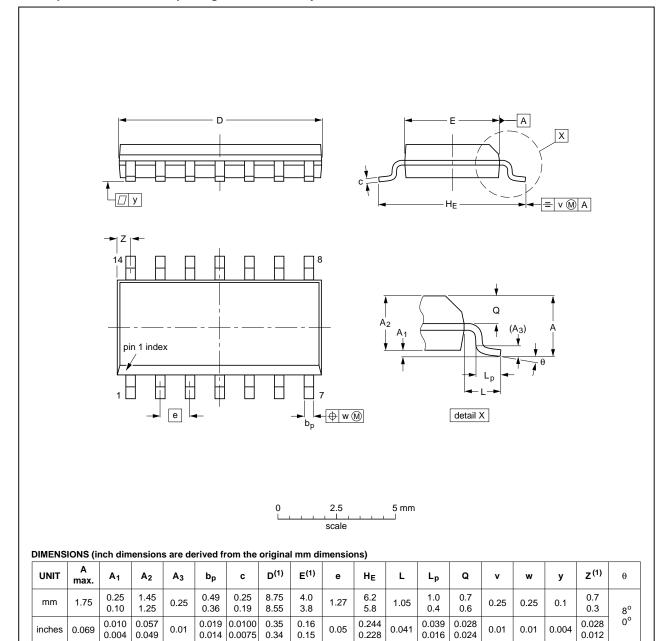
Fig 9. Package outline SOT27-1 (DIP14)

74ABT125

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SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

| OUTLINE VERSION | | REFER | EUROPEAN | ISSUE DATE | | |
|--------------------|--------|--------|----------|------------|------------|---------------------------------|
| | IEC | JEDEC | JEITA | | PROJECTION | ISSUE DATE |
| SOT108-1 | 076E06 | MS-012 | | | | 99-12-27 03-02-19 |

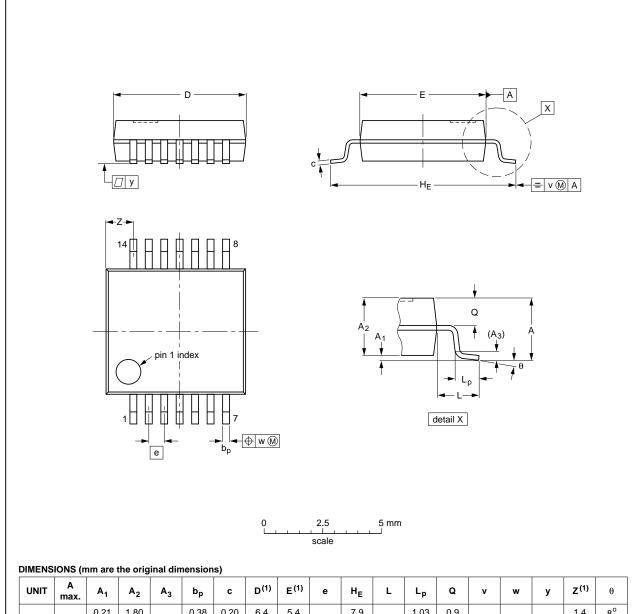
Fig 10. Package outline SOT108-1 (SO14)

74ABT12

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SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm

SOT337-1



| UNIT | A max. | A ₁ | A ₂ | A ₃ | bp | U | D ⁽¹⁾ | E ⁽¹⁾ | е | HE | L | Lp | ď | ٧ | ¥ | у | Z ⁽¹⁾ | θ |
|------|-----------|----------------|----------------|----------------|--------------|--------------|------------------|------------------|------|------------|------|--------------|------------|-----|------|-----|------------------|----------|
| mm | 2 | 0.21 0.05 | 1.80 1.65 | 0.25 | 0.38 0.25 | 0.20 0.09 | 6.4 6.0 | 5.4 5.2 | 0.65 | 7.9 7.6 | 1.25 | 1.03 0.63 | 0.9 0.7 | 0.2 | 0.13 | 0.1 | 1.4 0.9 | 8° 0° |

Note

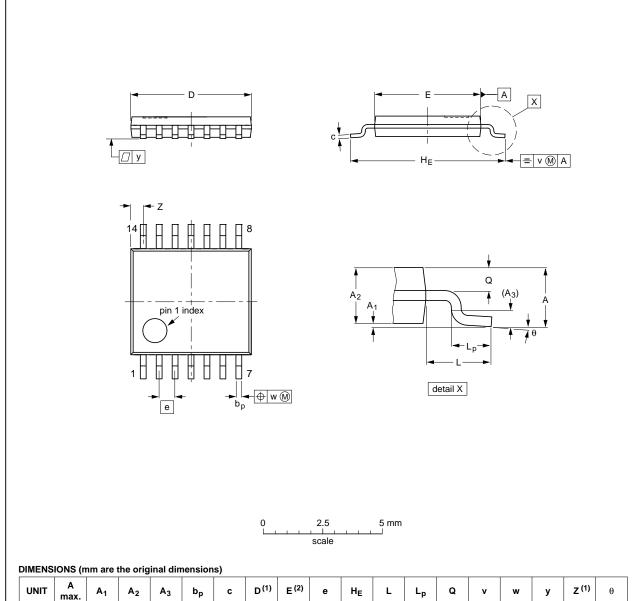
1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

| OUTLINE | | REFER | EUROPEAN | ISSUE DATE | | | | |
|----------|-----|--------|----------|------------|------------|---------------------------------|--|--|
| VERSION | IEC | JEDEC | JEITA | | PROJECTION | ISSUE DATE | | |
| SOT337-1 | | MO-150 | | | | 99-12-27 03-02-19 | | |

Fig 11. Package outline SOT337-1 (SSOP14)

TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1



| UNIT | A max. | A ₁ | A ₂ | A ₃ | bp | С | D ⁽¹⁾ | E ⁽²⁾ | е | HE | L | Lp | Q | v | w | у | Z ⁽¹⁾ | θ |
|------|-----------|----------------|----------------|----------------|--------------|------------|------------------|------------------|------|------------|---|--------------|------------|-----|------|-----|------------------|----------|
| mm | 1.1 | 0.15 0.05 | 0.95 0.80 | 0.25 | 0.30 0.19 | 0.2 0.1 | 5.1 4.9 | 4.5 4.3 | 0.65 | 6.6 6.2 | 1 | 0.75 0.50 | 0.4 0.3 | 0.2 | 0.13 | 0.1 | 0.72 0.38 | 8° 0° |

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

| OUTLINE | | REFER | EUROPEAN | ISSUE DATE | | | | |
|----------|-----|--------|----------|------------|------------|---------------------------------|--|--|
| VERSION | IEC | JEDEC | JEITA | | PROJECTION | ISSUE DATE | | |
| SOT402-1 | | MO-153 | | | | 99-12-27 03-02-18 | | |
| | | | | | | | | |

Fig 12. Package outline SOT402-1 (TSSOP14)

74ABT12

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DHVQFN14: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body 2.5 x 3 x 0.85 mm SOT762-1

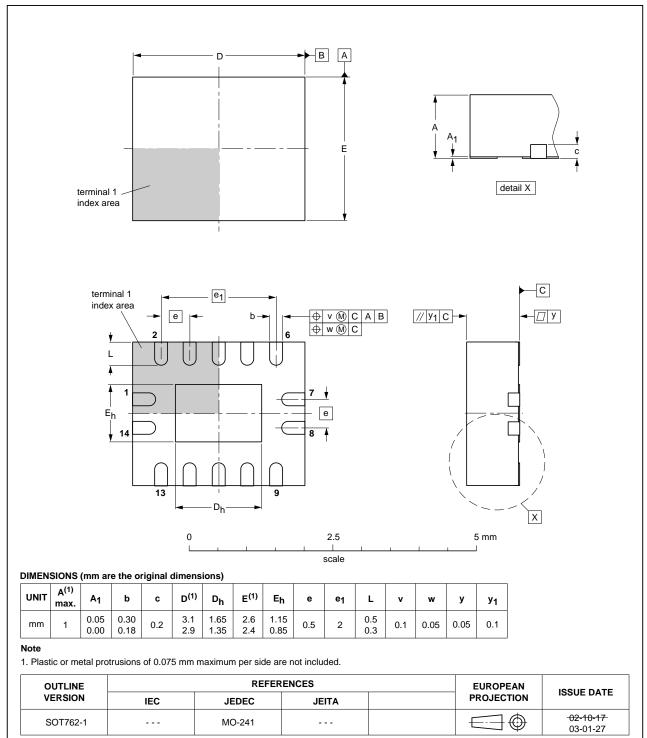


Fig 13. Package outline SOT762-1 (DHVQFN14)

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13. Abbreviations

Table 9. Abbreviations

| Acronym | Description |
|---------|-------------------------|
| BiCMOS | BipolarCMOS |
| DUT | Device Under Test |
| ESD | ElectroStatic Discharge |
| НВМ | Human Body Model |
| MM | Machine Model |

14. Revision history

Table 10. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|----------------|---------------------------------|-----------------------|---------------|--------------|
| 74ABT125 v.6 | 20111103 | Product data sheet | - | 74ABT125 v.5 |
| Modifications: | Legal pages | updated | | |
| 74ABT125 v.5 | 20101124 | Product data sheet | - | 74ABT125 v.4 |
| 74ABT125 v.4 | 20100427 | Product data sheet | - | 74ABT125 v.3 |
| 74ABT125 v.3 | 20080429 | Product data sheet | - | 74ABT125 v.2 |
| 74ABT125 v.2 | 19980116 | Product specification | - | 74ABT125 v.1 |
| 74ABT125 v.1 | 19960305 | - | - | - |

Quad buffer; 3-state

15. Legal information

15.1 Data sheet status

| Document status[1][2] | Product status[3] | Definition |
|--------------------------------|-------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

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- [2] The term 'short data sheet' is explained in section "Definitions"
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Quad buffer; 3-state

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